

KS03LL4

20W, 3V

Ultra Low Capacitance ESD Protection for High-Speed Interfaces

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-fre

DESCRIPTION

The device is designed to protect voltage sensitive electronic components from ESD and other transients. Its excellent clamping capability, low leakage, low capacitance and, fast response time provide the highest class protection on designs exposed to ESD.

The combination of small size, low capacitance and, high level ESD protection makes them a flexible solution for applications such as HDMI, Display Port TM and, MDDI interfaces. The device is designed to replace multiplayer varistors (MLV) in consumers' equipments such as mobile phone, notebook, PAD, STB, LCD TV etc.

APPLICATIONS

- · Audio and video equipment
- Portable devices
- · Computers and peripherals
- · Cellular handsets and accessories

FEATURES

- · Uni-directional ESD protection of four lines
- Low leakage current
- Low reverse clamping voltage
- · Fast response time

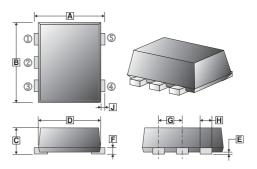
MARKING

5P

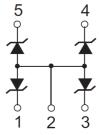
PACKAGE INFORMATION

Package	MPQ	Leader Size
SOT-553	3К	7 inch

SOT-553



REF.	Millimeter		חבר	Millimeter		
	Min.	Max.	REF.	Min.	Max.	
Α	1.50	1.70	F	0.09	0.16	
В	1.50	1.70	G	0.45	0.55	
C	0.525	0.60	Ι	0.17	0.27	
D	1.10	1.30	J	0.10	0.30	
E	-	0.05				



ABSOLUTE MAXIMUM RATINGS (T_A=25℃ unless otherwise specified)

Rating		Symbol	Value	Unit
IEC 61000-4-2 ESD Voltage ¹	Air model		±9	
	Contact model		±8	
JESD22-A114-B ESD Voltage ¹	Per human body model V _{ESD}		±15	kV
ESD Voltage ¹	Machine model		±0.4	
Peak Pulsed Power ²		РРК	20	W
Peak Pulsed Current ²		I _{PP}	2.5	Α
Maximum Lead temperature@ 10-second duration		T∟	260	Ĉ
Junction and Storage Temperature Range		T_J , T_{STG}	150, -55 ~ 150	G

Notes:

- 1. The device is stressed with 10 non-repetitive ESD pulses at per channel (I/O to GND).
- 2. According to IEC61000-4-5, the waveform of 8/20µs non-repetitive current pulse decays by exponents.

http://www.SeCoSGmbH.com/

Any changes of specification will not be informed individually.

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ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Reverse Working Voltage	V _{RWM}		-	-	3	V
Reverse Leakage Current	I _R	V _{RWM} =3V	-	-	1	μA
Reverse Breakdown Voltage	V_{BR}	I _T =1mA	5.3	-	5.9	V
Forward Voltage	VF	I _F =10mA	-	-	0.9	V
Clamping Voltage ¹	Vc	Ipp=2.5A	-	-	8	V
Junction Capacitance	CJ	V _R =0, f=1MHz	-	9	-	pF

Notes:

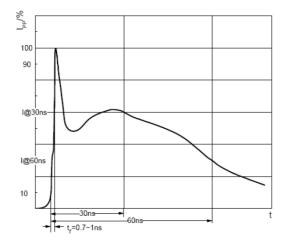
ESD STANDARDS COMPLIANCE

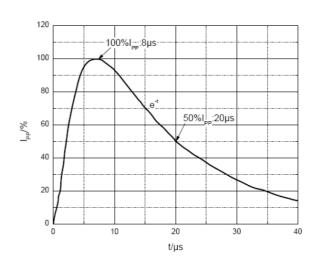
IEC61000-4-2 Standard

Contact Discharge		Air Discharge		
Level	Test Voltage kV	Level	Test Voltage kV	
1	2	1	2	
2	4	2	4	
3	6	3	8	
4	8	4	15	

JESD22-A114-B Standard

ESD Class	Human Body Discharge V	
0	0~249	
1A 1B 1C	250~499 500~999 1000~1999	
2	2000~3999	
3A	4000~7999	
3B	8000~15999	





ESD pulse waveform according to IEC61000-4-2

8/20µs pulse waveform according to IEC 61000-4-5

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CHARACTERISTICS CURVES

